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DMP4015SSS

Product Summary

BVDSS	Rds(on) Max	ID T _A = +25°C
-40V	11mΩ @ V _{GS} = -10V	-10.1A
	15mΩ @ V _{GS} = -4.5V	-8.8A

Description and Application

This new generation MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- DC-DC converters
- Power management functions
- Analog switches

P-CHANNEL ENHANCEMENT MODE MOSFET

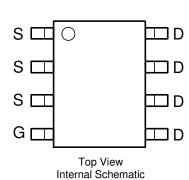
Features and Benefits

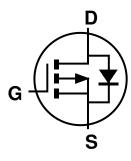
- 100% Unclamped Inductive Switch (UIS) Test in Production
 - Low Input Capacitance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability. https://www.diodes.com/quality/product-definitions/
- An Automotive-Compliant Part is Available Under Separate Datasheet (DMP4015SSSQ)

Mechanical Data

- Package: SO-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (63)
- Weight: 0.074 grams (Approximate)







Equivalent circuit

Ordering Information (Note 4)

Part Number	Paskaga	Packing		
	Package	Qty.	Carrier	
DMP4015SSS-13	SO-8	2,500	Tape & Reel	

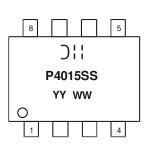
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



)|| = Manufacturer's Marking P4015SS = Product Type Marking Code YYWW = Date Code Marking YY or \overline{YY} = Year (ex: 22 = 2022) WW = Week (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	VDSS	-40	V		
Gate-Source Voltage			VGSS	±25	V
Continuous Drain Current (Note 5) $V_{GS} = -10V$	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	lo	-9.1 -7.2	А
Continuous Drain Current (Note 5) $V_{GS} = -4.5V$	Steady State	TA = +25°C TA = +70°C	lo	-7.8 -6.2	А
Continuous Drain Current (Note 6) $V_{GS} = -10V$	Steady State	TA = +25°C TA = +70°C	lo	-10.1 -8	А
Continuous Drain Current (Note 6) V_{GS} = -4.5V	Steady State	$T_{A} = +25^{\circ}C$ $T_{A} = +70^{\circ}C$	ID	-8.8 -7	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	ldм	-100	A		
Avalanche Current (Note 7)			IAS	-22	A
Avalanche Energy (Note 7)			EAS	242	mJ

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	1.45	W
Thermal Resistance, Junction to Ambient (Note 5)	Reja	88	°C/W
Total Power Dissipation (Note 6)	PD	1.82	W
Thermal Resistance, Junction to Ambient (Note 6)	Reja	70	°C/W
Thermal Resistance, Junction to Case (Note 6)	R _{θJc}	7.6	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Notes:

Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1inch square copper plate.

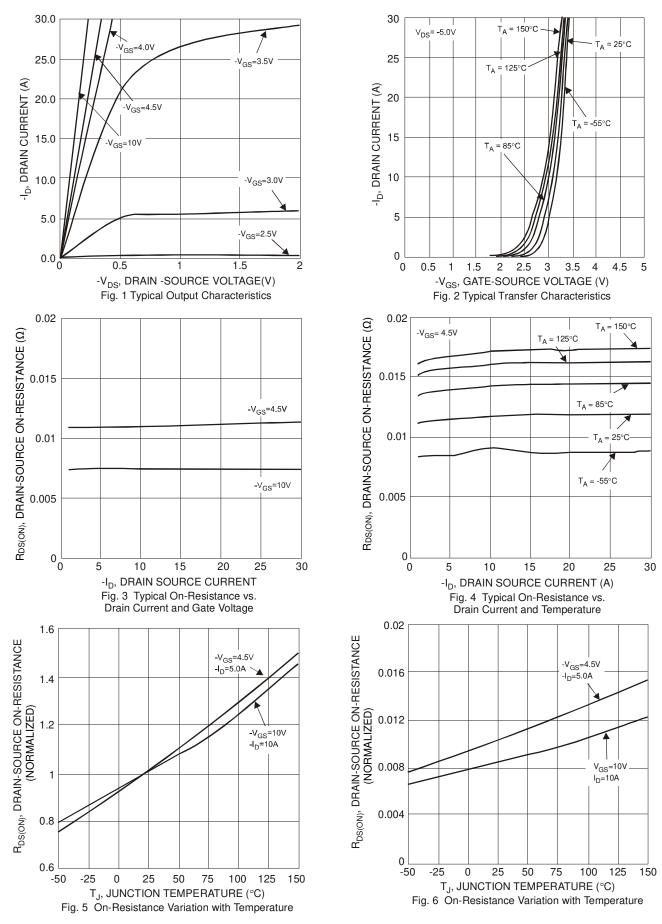
7. UIS in production with L = 1mH, T_J = +25°C.

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

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Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)		-			-		
Drain-Source Breakdown Voltage	BVDSS	-40	—		V	$V_{GS}=0V,\ I_{D}=-250\mu A$	
Zero Gate Voltage Drain Current	IDSS	—	—	-1	μA	$V_{DS} = -40V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	—	—	±100	nA	$V_{GS} = \pm 25V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	VGS(TH)	-1.5	-2	-2.5	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	
Static Drain-Source On-Resistance	Б	—	7	11	mΩ	$V_{GS} = -10V, I_D = -9.8A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	9	15	11122	$V_{GS} = -4.5V, I_D = -9.8A$	
Forward Transfer Admittance	Y _{fs}	_	26	_	S	V _{DS} = -20V, I _D = -9.8A	
Diode Forward Voltage (Note 5)	Vsd	_	-0.7	-1	V	$V_{GS} = 0V$, $I_S = -1A$	
DYNAMIC CHARACTERISTICS (Note 9)	-						
Input Capacitance	Ciss	_	4234				
Output Capacitance	Coss	_	1036	_	pF	$V_{DS} = -20V, V_{GS} = 0V$ f = 1MHz	
Reverse Transfer Capacitance	Crss	_	526	_			
Gate Resistance	Rg	—	7.77		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg	_	47.5	_			
Gate-Source Charge	Qgs	_	14.2	_	nC	V _{DS} = -20V, V _{GS} = -5V I _D = -9.8A	
Gate-Drain Charge	Q _{gd}	—	13.5	_			
Turn-On Delay Time	tD(ON)	—	13.2	—			
Turn-On Rise Time	tR	_	10			$\label{eq:VGS} \begin{array}{l} V_{GS} = -10V, V_{DD} = -20V, R_g = 6\Omega \\ I_D = -1A, R_L = 20\Omega \end{array}$	
Turn-Off Delay Time	tD(OFF)	_	302.7	_	ns		
Turn-Off Fall Time	tF	_	137.9	_			

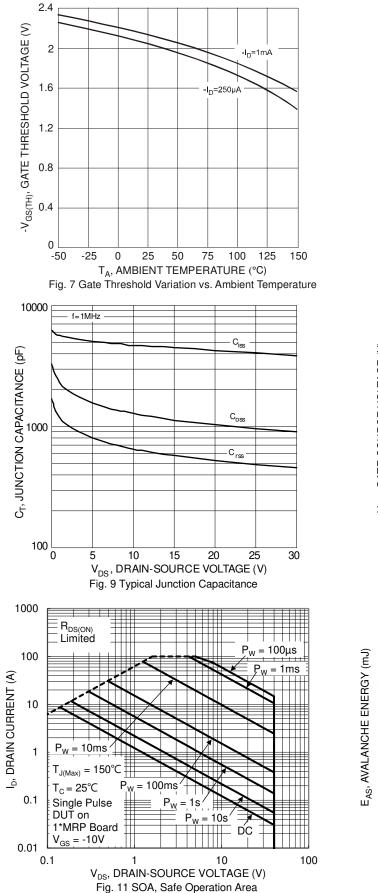
 Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing. Notes:

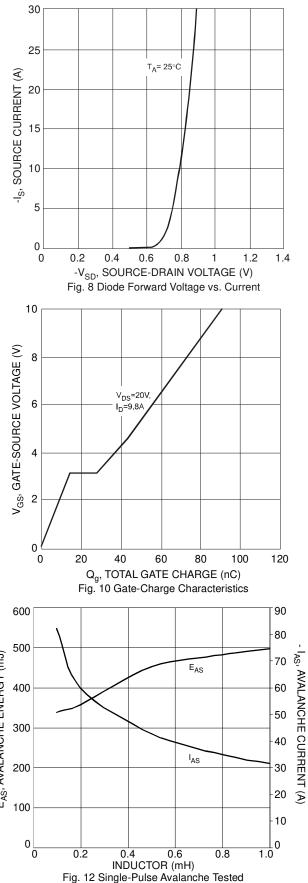




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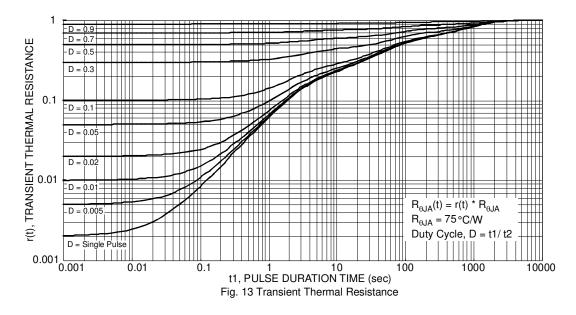






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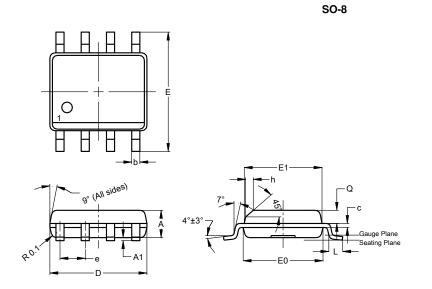






Package Outline Dimensions

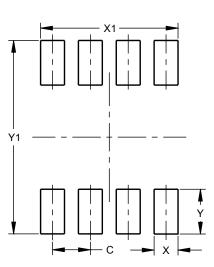
Please see http://www.diodes.com/package-outlines.html for the latest version.



SO-8					
Dim	Min	Max	Тур		
Α	1.40	1.50	1.45		
A1	0.10	0.20	0.15		
b	0.30	0.50	0.40		
С	0.15	0.25	0.20		
D	4.85	4.95	4.90		
Е	5.90	6.10	6.00		
E1	3.80	3.90	3.85		
E0	3.85	3.95	3.90		
е			1.27		
h	-		0.35		
L	0.62	0.82	0.72		
Q	0.60	0.70	0.65		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Di	mensions	Value (in mm)
	С	1.27
	Х	0.802
	X1	4.612
	Y	1.505
	V1	6 50

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SO-8



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